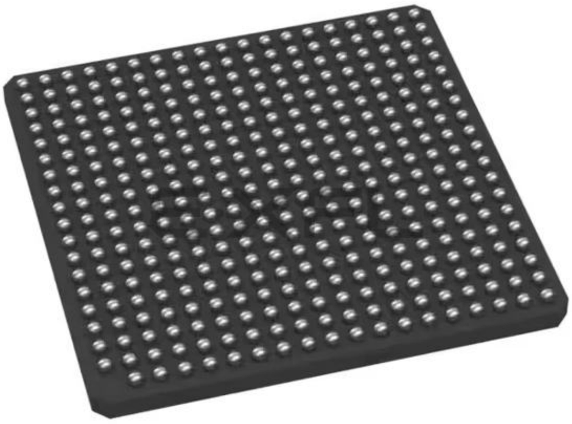

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC G4
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	1.7GHz
Co-Processors/DSP	Multimedia; SIMD
RAM Controllers	-
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	-
SATA	-
USB	-
Voltage - I/O	1.5V, 1.8V, 2.5V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	360-CLGA, FCCLGA
Supplier Device Package	360-FCCLGA (25x25)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc7448vs1700lc

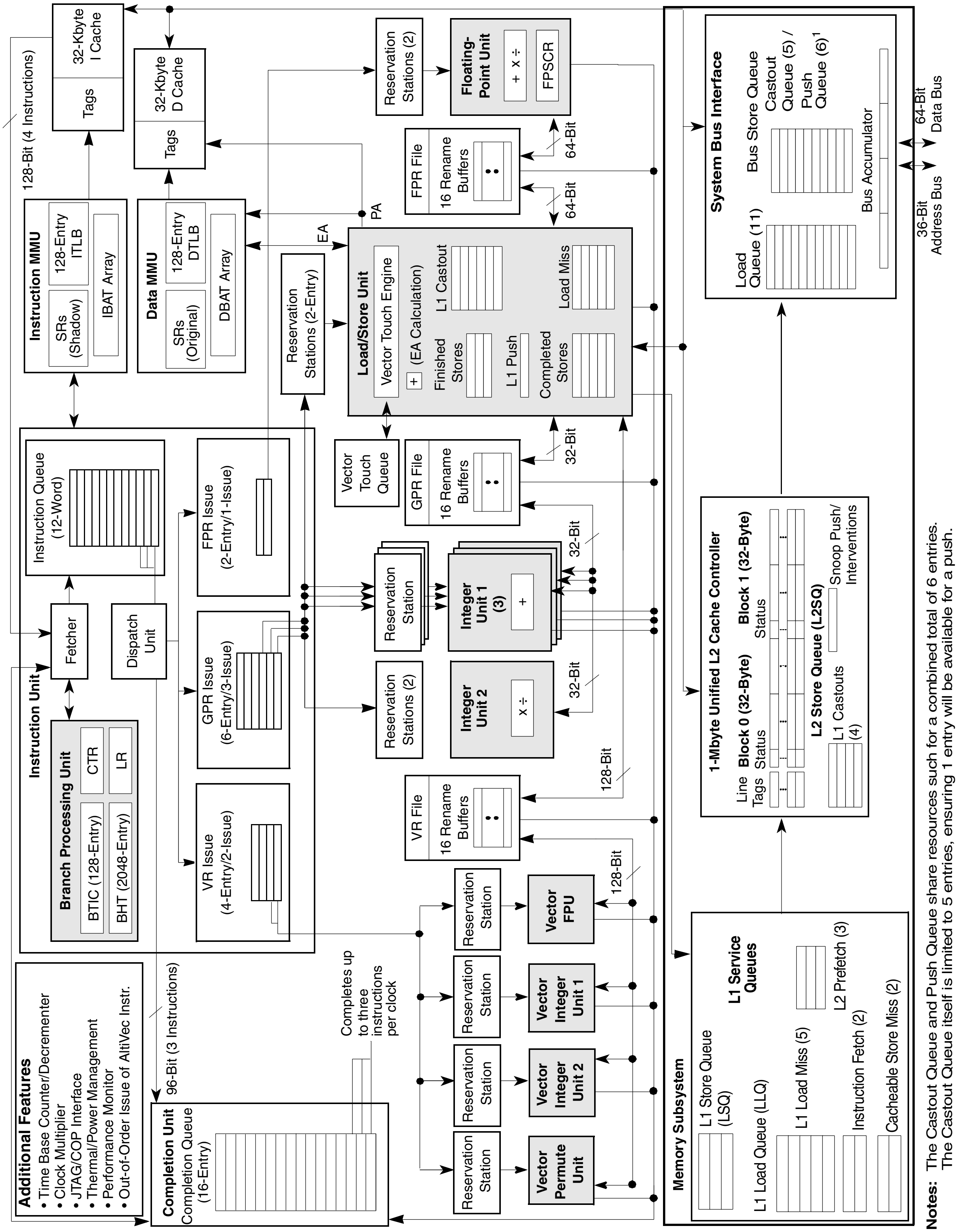


Figure 1. MPC7448 Block Diagram

- Four vector units and 32-entry vector register file (VRs)
  - Vector permute unit (VPU)
  - Vector integer unit 1 (VIU1) handles short-latency AltiVec™ integer instructions, such as vector add instructions (for example, **vaddsbs**, **vaddshs**, and **vaddsws**).
  - Vector integer unit 2 (VIU2) handles longer-latency AltiVec integer instructions, such as vector multiply add instructions (for example, **vmhaddshs**, **vmhraddshs**, and **vmladduhm**).
  - Vector floating-point unit (VFPU)
- Three-stage load/store unit (LSU)
  - Supports integer, floating-point, and vector instruction load/store traffic
  - Four-entry vector touch queue (VTQ) supports all four architected AltiVec data stream operations
  - Three-cycle GPR and AltiVec load latency (byte, half word, word, vector) with one-cycle throughput
  - Four-cycle FPR load latency (single, double) with one-cycle throughput
  - No additional delay for misaligned access within double-word boundary
  - A dedicated adder calculates effective addresses (EAs).
  - Supports store gathering
  - Performs alignment, normalization, and precision conversion for floating-point data
  - Executes cache control and TLB instructions
  - Performs alignment, zero padding, and sign extension for integer data
  - Supports hits under misses (multiple outstanding misses)
  - Supports both big- and little-endian modes, including misaligned little-endian accesses

- Three issue queues, FIQ, VIQ, and GIQ, can accept as many as one, two, and three instructions, respectively, in a cycle. Instruction dispatch requires the following:
  - Instructions can only be dispatched from the three lowest IQ entries—IQ0, IQ1, and IQ2.
  - A maximum of three instructions can be dispatched to the issue queues per clock cycle.
  - Space must be available in the CQ for an instruction to dispatch (this includes instructions that are assigned a space in the CQ but not in an issue queue).
- Rename buffers
  - 16 GPR rename buffers
  - 16 FPR rename buffers
  - 16 VR rename buffers
- Dispatch unit
  - Decode/dispatch stage fully decodes each instruction
- Completion unit
  - Retires an instruction from the 16-entry completion queue (CQ) when all instructions ahead of it have been completed, the instruction has finished executing, and no exceptions are pending
  - Guarantees sequential programming model (precise exception model)

- — Monitors all dispatched instructions and retires them in order
- — Tracks unresolved branches and flushes instructions after a mispredicted branch
- — Retires as many as three instructions per clock cycle
- Separate on-chip L1 instruction and data caches (Harvard architecture)
  - — 32-Kbyte, eight-way set-associative instruction and data caches
  - — Pseudo least-recently-used (PLRU) replacement algorithm
  - — 32-byte (eight-word) L1 cache block
  - — Physically indexed/physical tags
  - — Cache write-back or write-through operation programmable on a per-page or per-block basis
  - — Instruction cache can provide four instructions per clock cycle; data cache can provide four words per clock cycle
  - — Caches can be disabled in software.
  - — Caches can be locked in software.
  - — MESI data cache coherency maintained in hardware
  - — Separate copy of data cache tags for efficient snooping
  - — Parity support on cache
  - — No snooping of instruction cache except for **icbi** instruction
  - — Data cache supports AltiVec LRU and transient instructions
  - — Critical double- and/or quad-word forwarding is performed as needed. Critical quad-word forwarding is used for AltiVec loads and instruction fetches. Other accesses use critical double-word forwarding.
- Level 2 (L2) cache interface
  - — On-chip, 1-Mbyte, eight-way set-associative unified instruction and data cache
  - — Cache write-back or write-through operation programmable on a per-page or per-block basis
  - — Parity support on cache tags
  - — ECC or parity support on data
  - — Error injection allows testing of error recovery software
- Separate memory management units (MMUs) for instructions and data
  - — 52-bit virtual address, 32- or 36-bit physical address
  - — Address translation for 4-Kbyte pages, variable-sized blocks, and 256-Mbyte segments
  - — Memory programmable as write-back/write-through, caching-inhibited/caching-allowed, and memory coherency enforced/memory coherency not enforced on a page or block basis
  - — Separate IBATs and DBATs (eight each) also defined as SPRs
  - — Separate instruction and data translation lookaside buffers (TLBs)
    - – Both TLBs are 128-entry, two-way set-associative and use an LRU replacement algorithm.
    - – TLBs are hardware- or software-reloadable (that is, a page table search is performed in hardware or by system software on a TLB miss).

Table 5 provides the package thermal characteristics for the MPC7448. For more information regarding thermal management, see Section 9.7, “Power and Thermal Management Information.”

Table 5. Package Thermal Characteristics[1]

Characteristic	Symbol	Value	Unit	Notes
Junction-to-ambient thermal resistance, natural convection, single-layer (1s) board	$R_{\theta JA}$	26	•C/W	2, 3
Junction-to-ambient thermal resistance, natural convection, four-layer (2s2p) board	$R_{\theta JMA}$	19	•C/W	2, 4
Junction-to-ambient thermal resistance, 200 ft/min airflow, single-layer (1s) board	$R_{\theta JMA}$	22	•C/W	2, 4
Junction-to-ambient thermal resistance, 200 ft/min airflow, four-layer (2s2p) board	$R_{\theta JMA}$	16	•C/W	2, 4
Junction-to-board thermal resistance	$R_{\theta JB}$	11	•C/W	5
Junction-to-case thermal resistance	$R_{\theta JC}$	< 0.1	•C/W	6

Notes:
1. Refer to Section 9.7, “Power and Thermal Management Information,” for details about thermal management.
2. Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, airflow, power dissipation of other components on the board, and board thermal resistance.
3. Per JEDEC JESD51-2 with the single-layer board horizontal
4. Per JEDEC JESD51-6 with the board horizontal
5. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
6. This is the thermal resistance between die and case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the calculated case temperature. The actual value of $R_{\theta JC}$ for the part is less than 0.1°C/W.

Table 6 provides the DC electrical characteristics for the MPC7448.

Table 6. DC Electrical Specifications

At recommended operating conditions. See Table 4.

Characteristic	Nominal Bus Voltage [1]	Symbol	Min	Max	Unit	Notes
Input high voltage (all inputs)	1.5	V_{IH}	$OV_{DD} \times 0.65$	$OV_{DD} + 0.3$	V	2
	1.8		$OV_{DD} \times 0.65$	$OV_{DD} + 0.3$		
	2.5		1.7	$OV_{DD} + 0.3$		
Input low voltage (all inputs)	1.5	V_{IL}	–0.3	$OV_{DD} \times 0.35$	V	2
	1.8		–0.3	$OV_{DD} \times 0.35$		
	2.5		–0.3	0.7		
Input leakage current, all signals except BVSEL0, $\overline{\text{LSSD\_MODE}}$, $\overline{\text{TCK}}$, TDI, TMS, $\overline{\text{TRST}}$: $V_{in} = OV_{DD}$ $V_{in} = GND$	—	I_{in}	—	 50 – 50	μA	2, 3
Input leakage current, BVSEL0, $\overline{\text{LSSD\_MODE}}$, $\overline{\text{TCK}}$, TDI, TMS, $\overline{\text{TRST}}$: $V_{in} = OV_{DD}$ $V_{in} = GND$	—	I_{in}	—	 50 – 2000	μA	2, 6

Table 6. DC Electrical Specifications (continued)

At recommended operating conditions. See Table 4.

Characteristic		Nominal Bus Voltage [1]	Symbol	Min	Max	Unit	Notes
High-impedance (off-state) leakage current: $V_{in} = OV_{DD}$ V_{in} = GND		—	I_{TSI}	—	 50 – 50	μA	2, 3, 4
Output high voltage @ I_{OH} = –5 mA		1.5	V_{OH}	OV_{DD} – 0.45	—	V	
		1.8		OV_{DD} – 0.45	—		
		2.5		1.8	—		
Output low voltage @ I_{OL} = 5 mA		1.5	V_{OL}	—	0.45	V	
		1.8		—	0.45		
		2.5		—	0.6		
Capacitance, V_{in} = 0 V, f = 1 MHz	All inputs		C_{in}	—	8.0	pF	5

Notes:

1. Nominal voltages; see Table 4 for recommended operating conditions.
2. All I/O signals are referenced to OV_{DD}.
3. Excludes test signals and IEEE Std. 1149.1 boundary scan (JTAG) signals
4. The leakage is measured for nominal OV_{DD} and V_{DD}, or both OV_{DD} and V_{DD} must vary in the same direction (for example, both OV_{DD} and V_{DD} vary by either +5% or –5%).
5. Capacitance is periodically sampled rather than 100% tested.
6. These pins have internal pull-up resistors.

Table 7 provides the power consumption for the MPC7448 part numbers described by this document; see Section 11.1, "Part Numbers Fully Addressed by This Document," for information regarding which part numbers are described by this document. Freescale also offers MPC7448 part numbers that meet lower power consumption specifications by adhering to lower core voltage and core frequency specifications. For more information on these devices, including references to the MPC7448 Hardware Specification Addenda that describe these devices, see Section 11.2, "Part Numbers Not Fully Addressed by This Document."

The power consumptions provided in Table 7 represent the power consumption of each speed grade when operated at the rated maximum core frequency (see Table 8). Freescale sorts devices by power as well as by core frequency, and power limits for each speed grade are independent of each other. Each device is tested at its maximum core frequency only. (Note that Deep Sleep Mode power consumption is independent of clock frequency.) Operating a device at a frequency lower than its rated maximum is fully supported provided the clock frequencies are within the specifications given in Table 8, and a device operated below its rated maximum will have lower power consumption. However, inferences should not be made about a device's power consumption based on the power specifications of another (lower) speed grade. For example, a 1700 MHz device operated at 1420 MHz may not exhibit the same power consumption as a 1420 MHz device operated at 1420 MHz.

For all MPC7448 devices, the following guidelines on the use of these parameters for system design are suggested. The Full-Power Mode–Typical value represents the sustained power consumption of the device

Figure 6 provides the input/output timing diagram for the MPC7448.

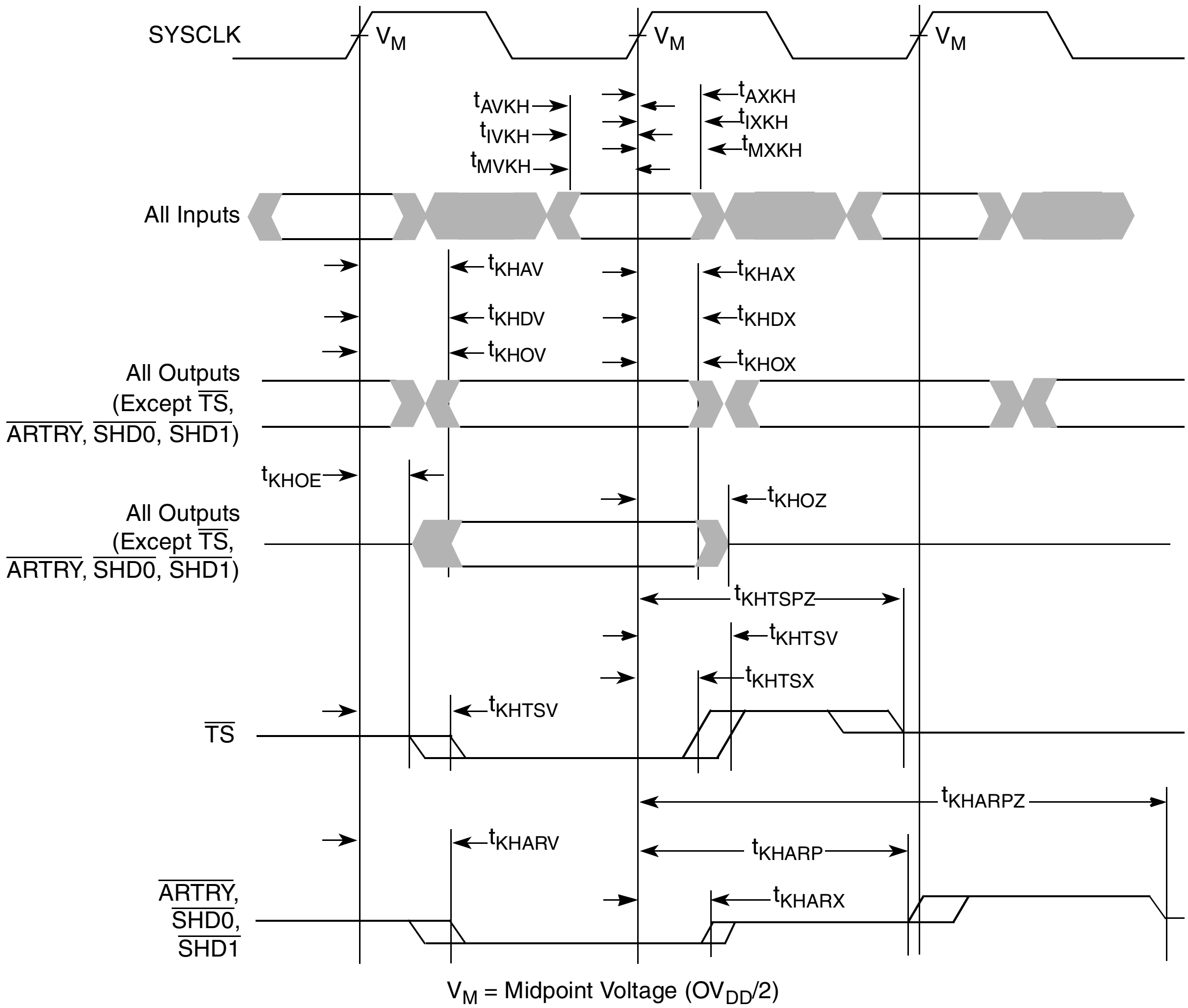


Figure 6. Input/Output Timing Diagram

Figure 7 provides the AC test load for TDO and the boundary-scan outputs of the MPC7448.

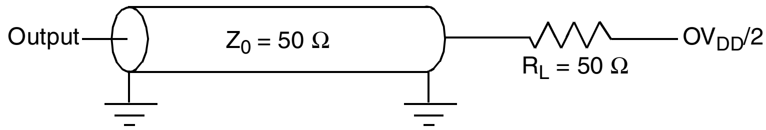


Figure 7. Alternate AC Test Load for the JTAG Interface

Figure 8 provides the JTAG clock input timing diagram.

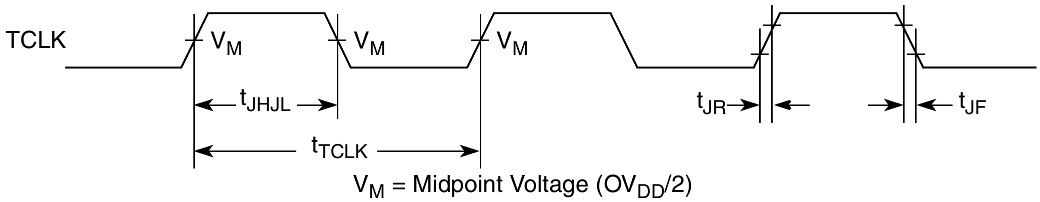


Figure 8. JTAG Clock Input Timing Diagram

Figure 9 provides the $\overline{\text{TRST}}$ timing diagram.

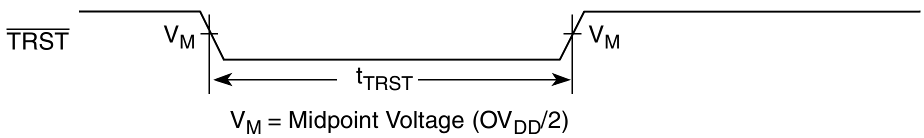


Figure 9. $\overline{\text{TRST}}$ Timing Diagram

Figure 10 provides the boundary-scan timing diagram.

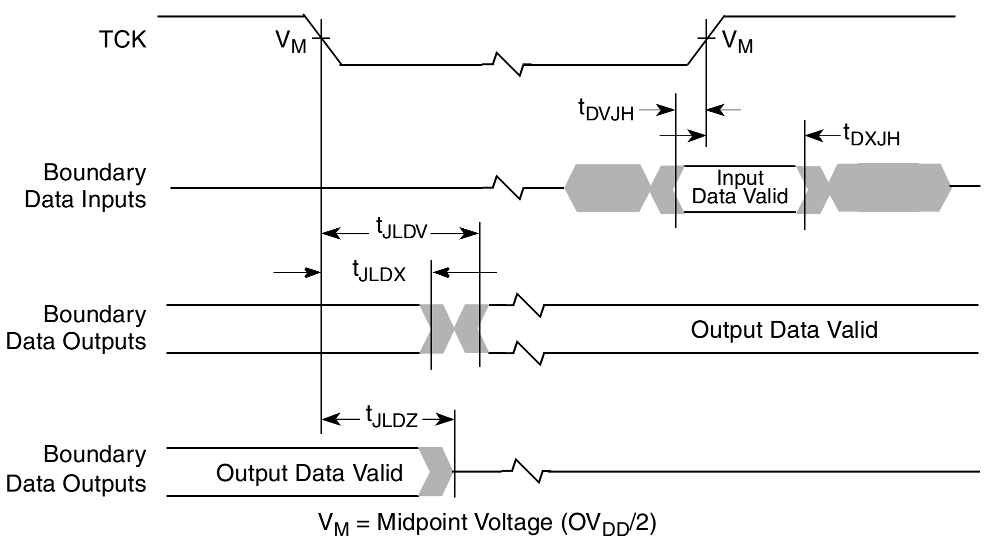


Figure 10. Boundary-Scan Timing Diagram

6 Pin Assignments

Figure 12 (in Part A) shows the pinout of the MPC7448, 360 high coefficient of thermal expansion ceramic ball grid array (HCTE) package as viewed from the top surface. Part B shows the side profile of the HCTE package to indicate the direction of the top surface view.

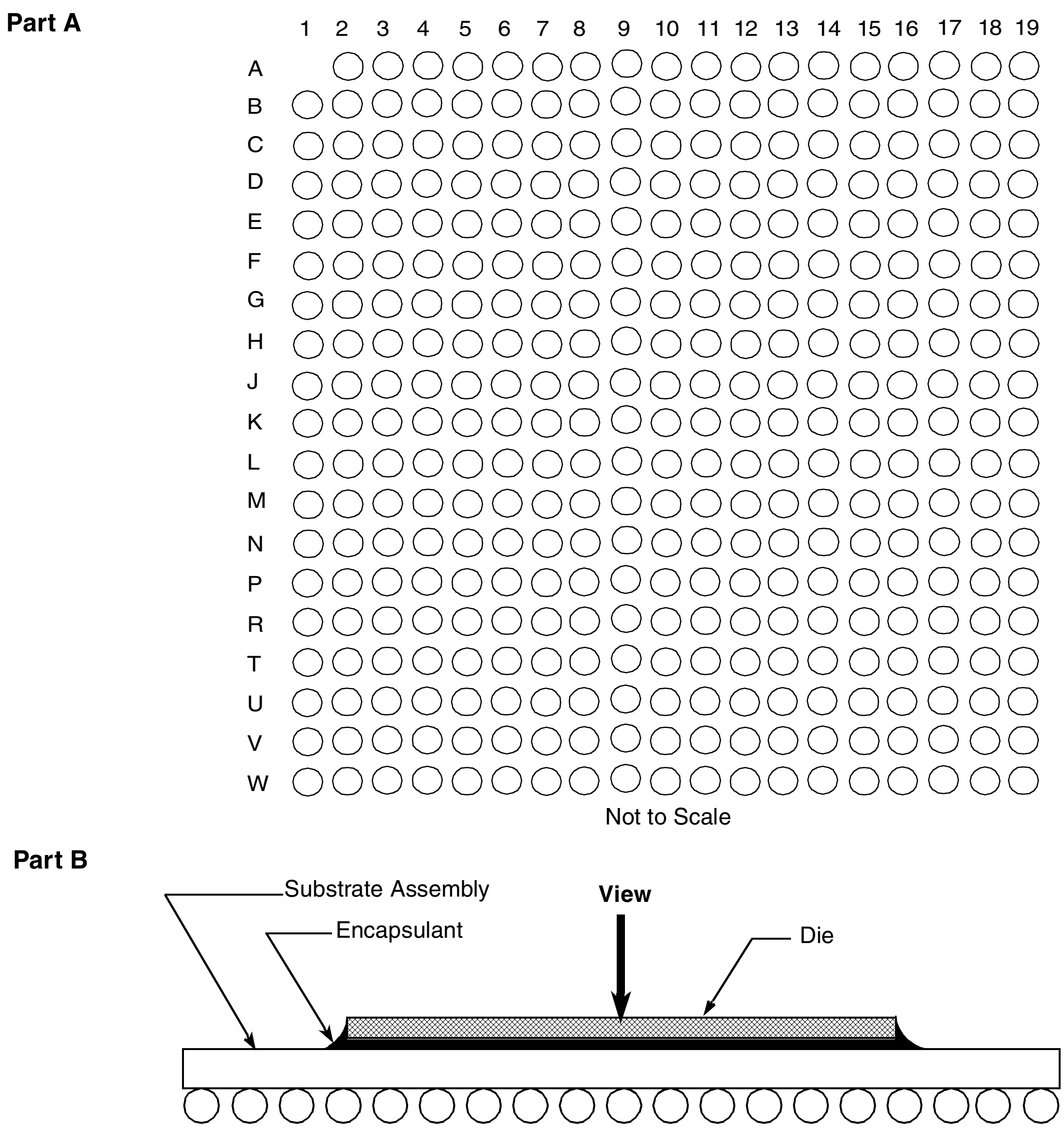


Figure 12. Pinout of the MPC7448, 360 HCTE Package as Viewed from the Top Surface

Table 11. Pinout Listing for the MPC7448, 360 HCTE Package

Signal Name	Pin Number	Active	I/O	Notes
A[0:35]	E11, H1, C11, G3, F10, L2, D11, D1, C10, G2, D12, L3, G4, T2, F4, V1, J4, R2, K5, W2, J2, K4, N4, J3, M5, P5, N3, T1, V2, U1, N5, W1, B12, C4, G10, B11	High	I/O	2
$\overline{\text{AACK}}$	R1	Low	Input	
AP[0:4]	C1, E3, H6, F5, G7	High	I/O	2
$\overline{\text{ARTRY}}$	N2	Low	I/O	3
AV_{DD}	A8	—	Input	
$\overline{\text{BG}}$	M1	Low	Input	
$\overline{\text{BMODE0}}$	G9	Low	Input	4
$\overline{\text{BMODE1}}$	F8	Low	Input	5
$\overline{\text{BR}}$	D2	Low	Output	
BVSEL0	B7	High	Input	1, 6
BVSEL1	E10	High	Input	1, 20
$\overline{\text{CI}}$	J1	Low	Output	
$\overline{\text{CKSTP\_IN}}$	A3	Low	Input	
$\overline{\text{CKSTP\_OUT}}$	B1	Low	Output	
CLK_OUT	H2	High	Output	
D[0:63]	R15, W15, T14, V16, W16, T15, U15, P14, V13, W13, T13, P13, U14, W14, R12, T12, W12, V12, N11, N10, R11, U11, W11, T11, R10, N9, P10, U10, R9, W10, U9, V9, W5, U6, T5, U5, W7, R6, P7, V6, P17, R19, V18, R18, V19, T19, U19, W19, U18, W17, W18, T16, T18, T17, W3, V17, U4, U8, U7, R7, P6, R8, W8, T8	High	I/O	
$\overline{\text{DBG}}$	M2	Low	Input	
$\overline{\text{DFS2}}$	A12	Low	Input	20, 21
$\overline{\text{DFS4}}$	B6	Low	Input	12, 20, 21
DP[0:7]	T3, W4, T4, W9, M6, V3, N8, W6	High	I/O	
$\overline{\text{DRDY}}$	R3	Low	Output	7
DTI[0:3]	G1, K1, P1, N1	High	Input	8
EXT_QUAL	A11	High	Input	9
$\overline{\text{GBL}}$	E2	Low	I/O	
GND	B5, C3, D6, D13, E17, F3, G17, H4, H7, H9, H11, H13, J6, J8, J10, J12, K7, K3, K9, K11, K13, L6, L8, L10, L12, M4, M7, M9, M11, M13, N7, P3, P9, P12, R5, R14, R17, T7, T10, U3, U13, U17, V5, V8, V11, V15	—	—	
GND	A17, A19, B13, B16, B18, E12, E19, F13, F16, F18, G19, H18, J14, L14, M15, M17, M19, N14, N16, P15, P19	—	—	15
GND_SENSE	G12, N13	—	—	19
$\overline{\text{HIT}}$	B2	Low	Output	7
$\overline{\text{HRESET}}$	D8	Low	Input	
$\overline{\text{INT}}$	D4	Low	Input	
L1_TSTCLK	G8	High	Input	9
L2_TSTCLK	B3	High	Input	10

Table 11. Pinout Listing for the MPC7448, 360 HCTE Package (continued)

Signal Name	Pin Number	Active	I/O	Notes
LVRAM	B10	—	—	12, 20, 22
NC (no connect)	A6, A14, A15, B14, B15, C14, C15, C16, C17, C18, C19, D14, D15, D16, D17, D18, D19, E14, E15, F14, F15, G14, G15, H15, H16, J15, J16, J17, J18, J19, K15, K16, K17, K18, K19, L15, L16, L17, L18, L19	—	—	11
LSSD_MODE	E8	Low	Input	6, 12
MCP	C9	Low	Input	
OV_{DD}	B4, C2, C12, D5, F2, H3, J5, K2, L5, M3, N6, P2, P8, P11, R4, R13, R16, T6, T9, U2, U12, U16, V4, V7, V10, V14	—	—	
OVDD_SENSE	E18, G18	—	—	16
PLL_CFG[0:4]	B8, C8, C7, D7, A7	High	Input	
PLL_CFG[5]	D10	High	Input	9, 20
PMON_IN	D9	Low	Input	13
PMON_OUT	A9	Low	Output	
QACK	G5	Low	Input	
QREQ	P4	Low	Output	
SHD[0:1]	E4, H5	Low	I/O	3
SMI	F9	Low	Input	
SRESET	A2	Low	Input	
SYSCLK	A10	—	Input	
TA	K6	Low	Input	
TBEN	E1	High	Input	
TBST	F11	Low	Output	
TCK	C6	High	Input	
TDI	B9	High	Input	6
TDO	A4	High	Output	
TEA	L1	Low	Input	
TEMP_ANODE	N18	—	—	17
TEMP_CATHODE	N19	—	—	17
TMS	F1	High	Input	6
TRST	A5	Low	Input	6, 14
TS	L4	Low	I/O	3
TSIZ[0:2]	G6, F7, E7	High	Output	
TT[0:4]	E5, E6, F6, E9, C5	High	I/O	
WT	D3	Low	Output	
V_{DD}	H8, H10, H12, J7, J9, J11, J13, K8, K10, K12, K14, L7, L9, L11, L13, M8, M10, M12	—	—	
V_{DD}	A13, A16, A18, B17, B19, C13, E13, E16, F12, F17, F19, G11, G16, H14, H17, H19, M14, M16, M18, N15, N17, P16, P18	—	—	15

Table 11. Pinout Listing for the MPC7448, 360 HCTE Package (continued)

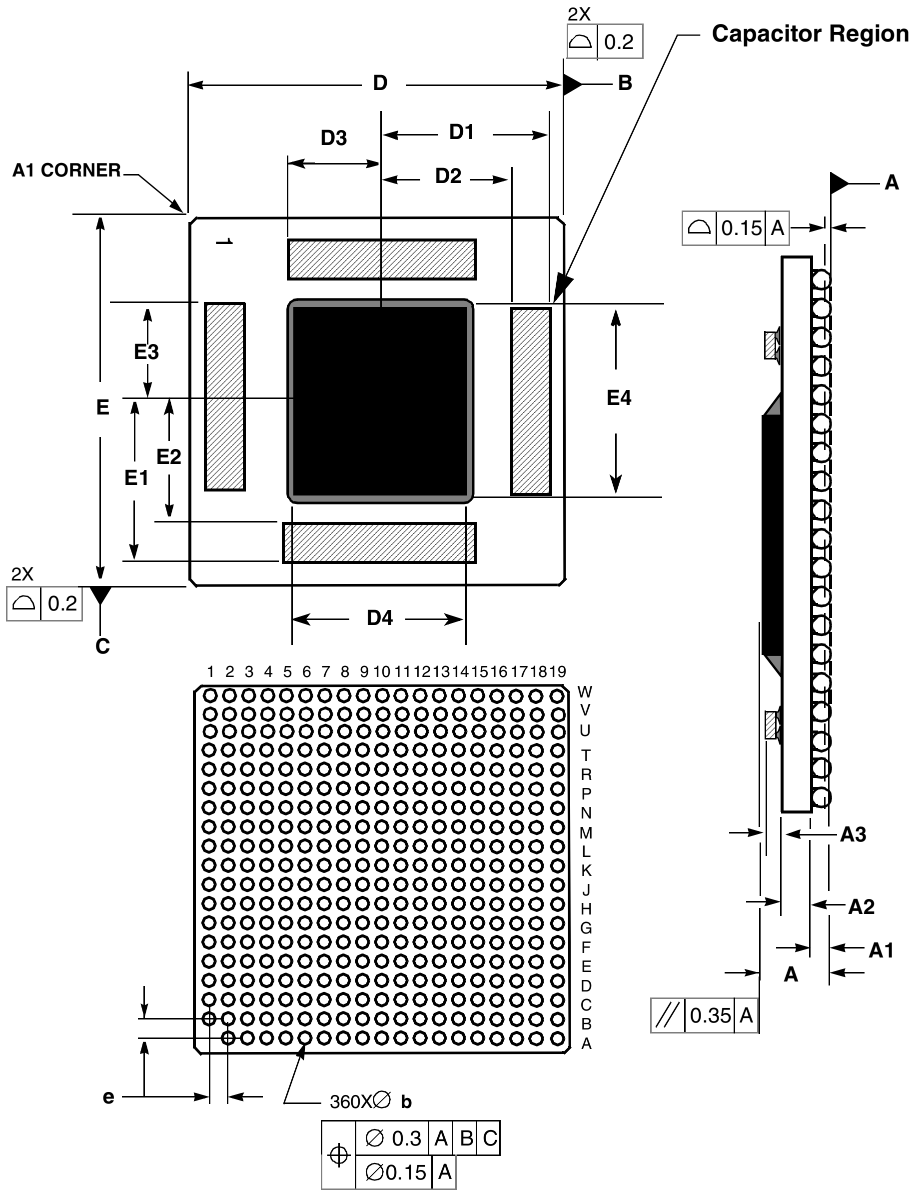
Signal Name	Pin Number	Active	I/O	Notes
VDD_SENSE	G13, N12	—	—	18

Notes:

1. OV_{DD} supplies power to the processor bus, JTAG, and all control signals, and is configurable. (V_{DD} supplies power to the processor core, and AV_{DD} supplies power to the PLL after filtering from V_{DD}). To program the I/O voltage, see Table 3. If used, the pull-down resistor should be less than 250 Ω. Because these settings may change in future products, it is recommended BVSEL[0:1] be configured using resistor options, jumpers, or some other flexible means, with the capability to reconfigure the termination of this signal in the future if necessary. For actual recommended value of V_{in} or supply voltages see Table 4.
2. Unused address pins must be pulled down to GND and corresponding address parity pins pulled up to OV_{DD}.
3. These pins require weak pull-up resistors (for example, 4.7 KΩ) to maintain the control signals in the negated state after they have been actively negated and released by the MPC7448 and other bus masters.
4. This signal selects between MPX bus mode (asserted) and 60x bus mode (negated) and will be sampled at $\overline{\text{HRESET}}$ going high.
5. This signal must be negated during reset, by pull-up resistor to OV_{DD} or negation by ¬$\overline{\text{HRESET}}$ (inverse of $\overline{\text{HRESET}}$), to ensure proper operation.
6. Internal pull up on die.
7. Not used in 60x bus mode.
8. These signals must be pulled down to GND if unused, or if the MPC7448 is in 60x bus mode.
9. These input signals are for factory use only and must be pulled down to GND for normal machine operation.
10. This test signal is recommended to be tied to $\overline{\text{HRESET}}$; however, other configurations will not adversely affect performance.
11. These signals are for factory use only and must be left unconnected for normal machine operation. Some pins that were NCs on the MPC7447, MPC7445, and MPC7441 have now been defined for other purposes.
12. These input signals are for factory use only and must be pulled up to OV_{DD} for normal machine operation.
13. This pin can externally cause a performance monitor event. Counting of the event is enabled through software.
14. This signal must be asserted during reset, by pull down to GND or assertion by $\overline{\text{HRESET}}$, to ensure proper operation.
15. These pins were NCs on the MPC7447, MPC7445, and MPC7441. See Section 9.3, “Connection Recommendations,” for more information.
16. These pins were OV_{DD} pins on the MPC7447, MPC7445, and MPC7441. These pins are internally connected to OV_{DD} and are intended to allow an external device (such as a power supply) to detect the I/O voltage level present inside the device package. If unused, it is recommended they be connected to test points to facilitate system debug; otherwise, they may be connected directly to OV_{DD} or left unconnected.
17. These pins provide connectivity to the on-chip temperature diode that can be used to determine the die junction temperature of the processor. These pins may be left unterminated if unused.
18. These pins are internally connected to V_{DD} and are intended to allow an external device (such as a power supply) to detect the processor core voltage level present inside the device package. If unused, it is recommended they be connected to test points to facilitate system debug; otherwise, they may be connected directly to V_{DD} or left unconnected.
19. These pins are internally connected to GND and are intended to allow an external device to detect the processor ground voltage level present inside the device package. If unused, it is recommended they be connected to test points to facilitate system debug; otherwise, they may be connected directly to GND or left unconnected.
20. These pins were in the TEST[0:4] factory test pin group on the MPC7447A, MPC7447, MPC7445, and MPC7441. They have been assigned new functions on the MPC7448.
21. These pins can be used to enable the supported dynamic frequency switching (DFS) modes via hardware. If both are pulled down, DFS mode is disabled completely and cannot be enabled via software. If unused, they should be pulled up to OV_{DD} to allow software control of DFS. See the *MPC7450 RISC Microprocessor Family Reference Manual* for more information.
22. This pin is provided to allow operation of the L2 cache at low core voltages and is for factory use only. See the *MPC7450 RISC Microprocessor Family Reference Manual* for more information.

8.2 Mechanical Dimensions for the MPC7448, 360 HCTE BGA

Figure 13 provides the mechanical dimensions and bottom surface nomenclature for the MPC7448, 360 HCTE BGA package.



NOTES:
1. Dimensioning and tolerancing per ASME Y14.5M, 1994
2. Dimensions in millimeters.
3. Top side A1 corner index is a metalized feature with various shapes. Bottom side A1 corner is designated with a ball missing from the array.

	Millimeters	
Dim	Min	Max
A	2.32	2.80
A1	0.80	1.00
A2	0.70	0.90
A3	—	0.6
b	0.82	0.93
D	25.00 BSC	
D1	—	11.3
D2	8.0	—
D3	—	6.5
D4	7.2	7.4
e	1.27 BSC	
E	25.00 BSC	
E1	—	11.3
E2	8.0	—
E3	—	6.5
E4	7.9	8.1

Figure 13. Mechanical Dimensions and Bottom Surface Nomenclature for the MPC7448, 360 HCTE BGA Package

8.5 Package Parameters for the MPC7448, 360 HCTE RoHS-Compliant BGA

The package parameters are as provided in the following list. The package type is 25 × 25 mm, 360-lead high coefficient of thermal expansion ceramic ball grid array (HCTE) with RoHS-compliant lead-free spheres.

Package outline	25 × 25 mm
Interconnects	360 (19 × 19 ball array – 1)
Pitch	1.27 mm (50 mil)
Minimum module height	1.92 mm
Maximum module height	2.40 mm
Ball diameter	0.75 mm (30 mil)
Coefficient of thermal expansion	12.3 ppm/°C

Table 12. MPC7448 Microprocessor PLL Configuration Example (continued)

PLL_CFG[0:5]	Example Core and VCO Frequency in MHz										
	Bus-to-Core Multiplier [5]	Core-to-VCO Multiplier [5]	Bus (SYSCLK) Frequency								
			33.3 MHz	50 MHz	66.6 MHz	75 MHz	83 MHz	100 MHz	133 MHz	167 MHz	200 MHz
100110	11x	1x			733	825	913	1100	1467		
000000	11.5x	1x			766	863	955	1150	1533		
101110	12x	1x		600	800	900	996	1200	1600		
111110	12.5x	1x		625	833	938	1038	1250	1667		
010110	13x	1x		650	865	975	1079	1300			
111000	13.5x	1x		675	900	1013	1121	1350			
110010	14x	1x		700	933	1050	1162	1400			
000110	15x	1x		750	1000	1125	1245	1500			
110110	16x	1x		800	1066	1200	1328	1600			
000010	17x	1x		850	1132	1275	1417	1700			
001010	18x	1x	600	900	1200	1350	1500				
001110	20x	1x	667	1000	1332	1500	1666				
010010	21x	1x	700	1050	1399	1575					
011010	24x	1x	800	1200	1600						
111010	28x	1x	933	1400							
001100	PLL bypass		PLL off, SYSCLK clocks core circuitry directly								
111100	PLL off		PLL off, no core clocking occurs								

Notes:

1. PLL_CFG[0:5] settings not listed are reserved.
2. The sample bus-to-core frequencies shown are for reference only. Some PLL configurations may select bus, core, or VCO frequencies which are not useful, not supported, or not tested for by the MPC7448; see Section 5.2.1, "Clock AC Specifications," for valid SYSCLK, core, and VCO frequencies.
3. In PLL-bypass mode, the SYSCLK input signal clocks the internal processor directly and the PLL is disabled. However, the bus interface unit requires a 2x clock to function. Therefore, an additional signal, EXT_QUAL, must be driven at half the frequency of SYSCLK and offset in phase to meet the required input setup t_{IVKH} and hold time t_{IXKH} (see Table 9). The result will be that the processor bus frequency will be one-half SYSCLK, while the internal processor is clocked at SYSCLK frequency. This mode is intended for factory use and emulator tool use only.
   Note: The AC timing specifications given in this document do not apply in PLL-bypass mode.
4. In PLL-off mode, no clocking occurs inside the MPC7448 regardless of the SYSCLK input.
5. Applicable when DFS modes are disabled. These multipliers change when operating in a DFS mode. See Section 9.7.5, "Dynamic Frequency Switching (DFS)" for more information.
6. Bus-to-core multipliers less than 5x require that assertion of AACK be delayed by one or two bus cycles to allow the processor to generate a response to a snooped transaction. See the *MPC7450 RISC Microprocessor Reference Manual* for more information.

These requirements are shown graphically in Figure 16.

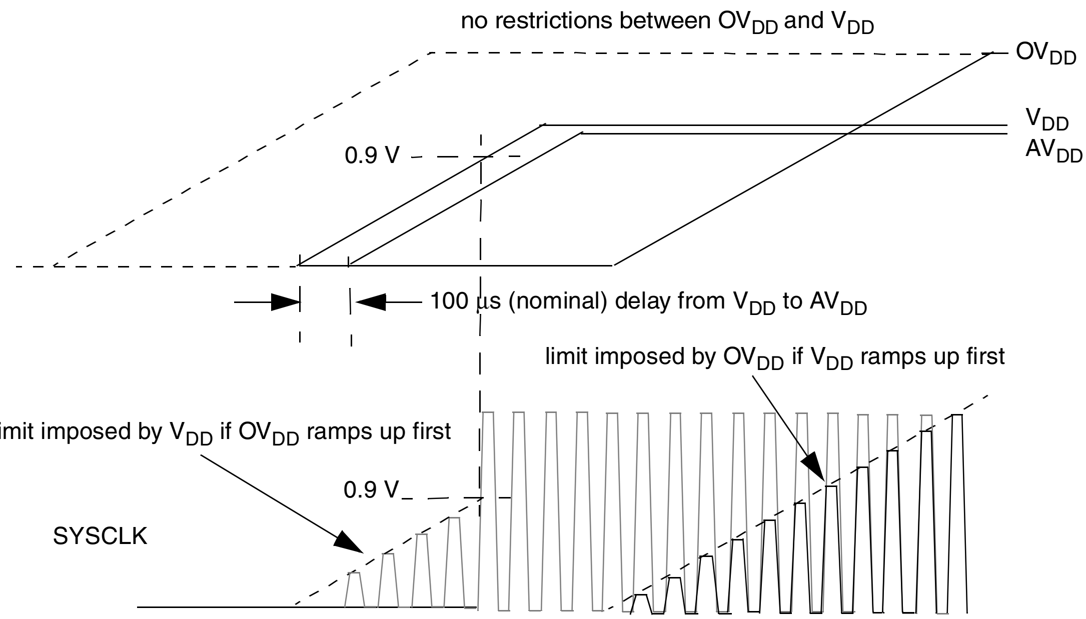


Figure 16. MPC7448 Power Up Sequencing Requirements

Certain stipulations also apply to the manner in which the power rails of the MPC7448 power down, as follows:

- OV_{DD} may ramp down any time before or after V_{DD}.
- The voltage at the SYSCLK input must not exceed V_{DD} once V_{DD} has ramped down below 0.9 V.
- The voltage at the SYSCLK input must not exceed OV_{DD} by more 20% during transients (see overshoot/undershoot specifications in Figure 2) or 0.3 V DC (see Table 2) at any time.

9.2.3 Transient Specifications

The ensure the long-term reliability of the device, the MPC7448 requires that transients on the core power rail (V_{DD}) be constrained. The recommended operating voltage specifications provided in Table 4 are DC specifications. That is, the device may be operated continuously with V_{DD} within the specified range without adversely affecting the device's reliability. Excursions above the stated recommended operation range, including overshoot during power-up, can impact the long-term reliability of the device. Excursions are described by their amplitude and duration. Duration is defined as the time period during which the V_{DD} power plane, as measured at the VDD_SENSE pins, will be within a specific voltage range, expressed as percentage of the total time the device will be powered up over the device lifetime. In practice, the period over which transients are measured can be any arbitrary period of time that accurately represents the expected range of processor and system activity. The voltage ranges and durations for normal operation and transients are described in Table 14.

Table 14. VDD Power Supply Transient Specifications

At recommended operating temperatures. See Table 4.

Voltage Region	Voltage Range (V)		Permitted Duration [1]	Notes
	Min	Max		
Normal	V_{DD} minimum	V_{DD} maximum	100%	2
Low Transient	V_{DD} maximum	1.35 V	10%	2, 3
High Transient	1.35 V	1.40 V	0.2%	4

Notes:

1. Permitted duration is defined as the percentage of the total time the device is powered on that the V_{DD} power supply voltage may exist within the specified voltage range.
2. See Table 4 for nominal V_{DD} specifications.
3. To simplify measurement, excursions into the High Transient region are included in this duration.
4. Excursions above the absolute maximum rating of 1.4 V are not permitted; see Table 2.

Note that, to simplify transient measurements, the duration of the excursion into the High Transient region is also included in the Low Transient duration, so that only the time the voltage is above each threshold must be considered. Figure 19 shows an example of measuring voltage transients.

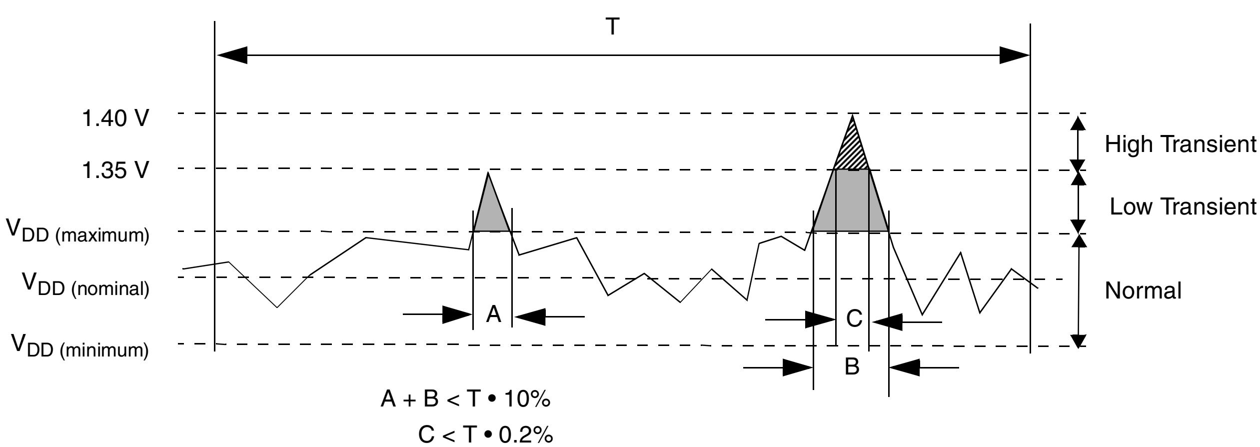


Figure 19. Voltage Transient Example

of any thermal interface material depends on many factors—thermal performance requirements, manufacturability, service temperature, dielectric properties, cost, and so on.

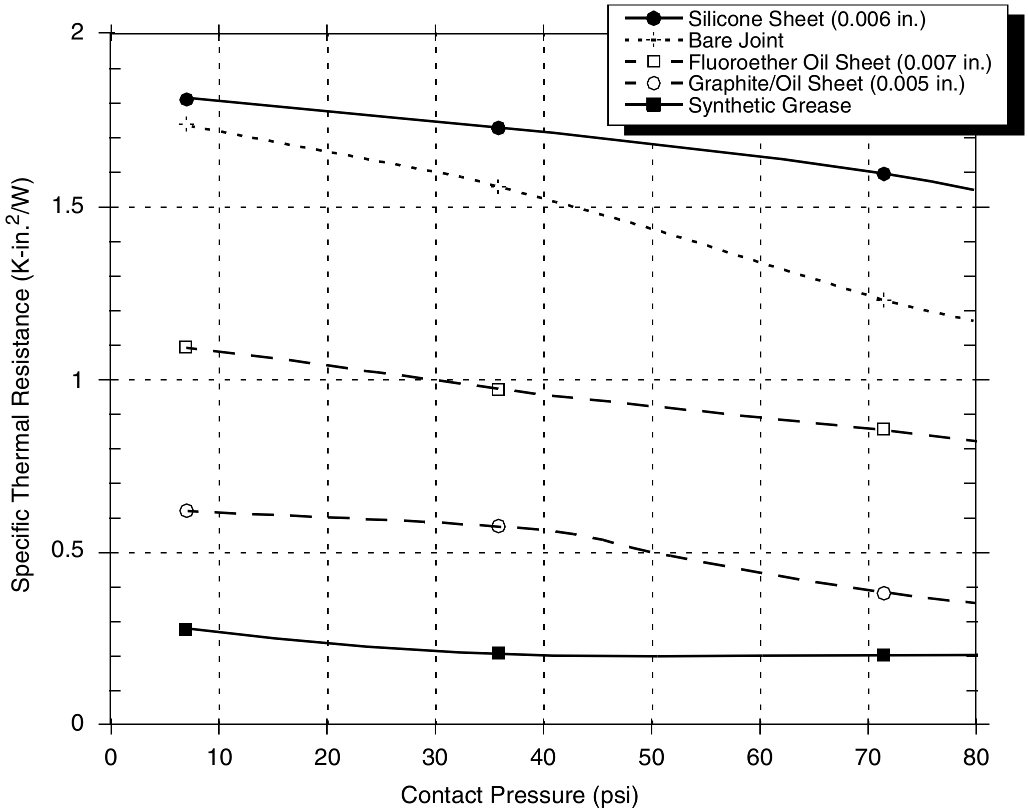


Figure 25. Thermal Performance of Select Thermal Interface Material

The board designer can choose between several types of thermal interfaces. Heat sink adhesive materials should be selected based on high conductivity and mechanical strength to meet equipment shock/vibration requirements. There are several commercially available thermal interfaces and adhesive materials provided by the following vendors:

The Bergquist Company — 800-347-4572
18930 West 78th St.
Chanhassen, MN 55317
Internet: www.bergquistcompany.com

Chomerics, Inc. — 781-935-4850
77 Dragon Ct.
Woburn, MA 01801
Internet: www.chomerics.com

Dow-Corning Corporation — 800-248-2481
Corporate Center
P.O. Box 994.
Midland, MI 48686-0994
Internet: www.dowcorning.com

Shin-Etsu MicroSi, Inc. 10028 S. 51st St. Phoenix, AZ 85044 Internet: www.microsi.com	888-642-7674
Laird Technologies - Thermal (formerly Thermagon Inc.) 4707 Detroit Ave. Cleveland, OH 44102 Internet: www.lairdtech.com	888-246-905

The following section provides a heat sink selection example using one of the commercially available heat sinks.

9.7.3 Heat Sink Selection Example

For preliminary heat sink sizing, the die-junction temperature can be expressed as follows:

$$T_j = T_i + T_r + (R_{\theta JC} + R_{\theta int} + R_{\theta sa}) \times P_d$$

where:

T_j is the die-junction temperature
T_i is the inlet cabinet ambient temperature
T_r is the air temperature rise within the computer cabinet
$R_{\theta JC}$ is the junction-to-case thermal resistance
$R_{\theta int}$ is the adhesive or interface material thermal resistance
$R_{\theta sa}$ is the heat sink base-to-ambient thermal resistance
P_d is the power dissipated by the device

During operation, the die-junction temperatures (T_j) should be maintained less than the value specified in Table 4. The temperature of air cooling the component greatly depends on the ambient inlet air temperature and the air temperature rise within the electronic cabinet. An electronic cabinet inlet-air temperature (T_i) may range from 30° to 40°C. The air temperature rise within a cabinet (T_r) may be in the range of 5° to 10°C. The thermal resistance of the thermal interface material ($R_{\theta int}$) is typically about 1.1 °C/W. For example, assuming a T_i of 30°C, a T_r of 5°C, an HCTE package $R_{\theta JC}$ = 0.1, and a power consumption (P_d) of 25.6 W, the following expression for T_j is obtained:

Die-junction temperature: $T_j = 30°C + 5°C + (0.1°C/W + 1.1°C/W + \theta_{sa}) \times 25.6$

For this example, a $R_{\theta sa}$ value of 1.53 °C/W or less is required to maintain the die junction temperature below the maximum value of Table 4.

Though the die junction-to-ambient and the heat sink-to-ambient thermal resistances are a common figure-of-merit used for comparing the thermal performance of various microelectronic packaging technologies, one should exercise caution when only using this metric in determining thermal management because no single parameter can adequately describe three-dimensional heat flow. The final die-junction operating temperature is not only a function of the component-level thermal resistance, but the system-level design and its operating conditions. In addition to the component's power consumption, a number of factors affect the final operating die-junction temperature—airflow, board population (local heat flux of adjacent components), heat sink efficiency, heat sink attach, heat sink placement, next-level interconnect technology, system air temperature rise, altitude, and so on.

Solving for T, the equation becomes:

$$\mathbf{nT} = \frac{V_H - V_L}{1.986 \times 10^{-4}}$$

9.7.5 Dynamic Frequency Switching (DFS)

The DFS feature in the MPC7448 adds the ability to divide the processor-to-system bus ratio by two or four during normal functional operation. Divide-by-two mode is enabled by setting the HID1[DFS2] bit in software or by asserting the $\overline{\text{DFS2}}$ pin via hardware. The MPC7448 can be returned for full speed by clearing HID1[DFS2] or negating $\overline{\text{DFS2}}$. Similarly, divide-by-four mode is enabled by setting HID1[DFS4] in software or by asserting the $\overline{\text{DFS4}}$ pin. In all cases, the frequency change occurs in 1 clock cycle and no idle waiting period is required to switch between modes. Note that asserting either $\overline{\text{DFS2}}$ or $\overline{\text{DFS4}}$ overrides software control of DFS, and that asserting both $\overline{\text{DFS2}}$ and $\overline{\text{DFS4}}$ disables DFS completely, including software control. Additional information regarding DFS can be found in the *MPC7450 RISC Microprocessor Family Reference Manual*. Note that minimum core frequency requirements must be observed when enabling DFS, and the resulting core frequency must meet the requirements for f_{core_DFS} given in Table 8.

9.7.5.1 Power Consumption with DFS Enabled

Power consumption with DFS enabled can be approximated using the following formula:

$$\mathbf{P_{DFS}} = \left[\frac{f_{DFS}}{f}\ (\mathbf{P} - \mathbf{P_{DS}})\right] + \mathbf{P_{DS}}$$

Where:

P_{DFS} = Power consumption with DFS enabled

f_{DFS} = Core frequency with DFS enabled

f = Core frequency prior to enabling DFS

P = Power consumption prior to enabling DFS (see Table 7)

P_{DS} = Deep sleep mode power consumption (see Table 7)

The above is an approximation only. Power consumption with DFS enabled is not tested or guaranteed.

9.7.5.2 Bus-to-Core Multiplier Constraints with DFS

DFS is not available for all bus-to-core multipliers as configured by PLL_CFG[0:5] during hard reset. The complete listing is shown in Table 16. Shaded cells represent DFS modes that are not available for a particular PLL_CFG[0:5] setting. Should software or hardware attempt to transition to a multiplier that is not supported, the device will remain at its current multiplier. For example, if a transition from DFS-disabled to an unsupported divide-by-2 or divide-by-4 setting is attempted, the bus-to-core multiplier will remain at the setting configured by the PLL_CFG[0:5] pins. In the case of an attempted transition from a supported divide-by-2 mode to an unsupported divide-by-4 mode, the device will remain in divide-by-2 mode. In all cases, the HID1[PC0-5] bits will correctly reflect the current bus-to-core frequency multiplier.

Table 20. Part Numbers Addressed by MC7448T*xxnnnn*N*x* Series Hardware Specification Addendum (Document Order No. MPC7448ECS02AD)

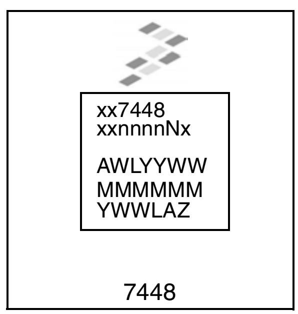
xx	7448	T	*xx*	*nnnn*	N	*x*
Product Code	**Part Identifier**	**Specification Modifier**	**Package**	**Processor Frequency**	**Application Modifier**	**Revision Level**
MC PPC[1]	7448	T = Extended Temperature Device	HX = HCTE BGA	1400	N: 1.15 V ± 50 mV – 40 to 105 °C	C: 2.1; PVR = 0x8004_0201 D: 2.2; PVR = 0x8004_0202
				1267 Revision C only	N: 1.1 V ± 50 mV – 40 to 105 °C	
				1267 Revision D only	N: 1.05 V ± 50 mV – 40 to 105 °C	
				1000	N: 1.0 V ± 50 mV – 40 to 105 °C	

Notes:

1. The P prefix in a Freescale part number designates a “Pilot Production Prototype” as defined by Freescale SOP 3-13. These parts have only preliminary reliability and characterization data. Before pilot production prototypes can be shipped, written authorization from the customer must be on file in the applicable sales office acknowledging the qualification status and the fact that product changes may still occur as pilot production prototypes are shipped.

11.3 Part Marking

Parts are marked as the example shown in Figure 27.



BGA/LGA

Notes:

AWLYYWW is the test code, where YYWW is the date code (YY = year, WW = work week)
MMMMMM is the M00 (mask) number.
YWWLAZ is the assembly traceability code.

Figure 27. Part Marking for BGA and LGA Device